

Advance GTVA101K42EV

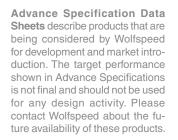
Thermally-Enhanced High Power RF GaN on SiC HEMT 1400 W, 50 V, 960 - 1215 MHz

Description

The GTVA101K42EV is a 1400-watt GaN on SiC high electron mobility transistor (HEMT) for use in multi-standard cellular power amplifier applications. It features input matching, high efficiency, and a thermally-enhanced surface-mount package with bolt-down flange.

Features

- GaN on SiC HEMT technology
- Input matched
- Typical Pulsed CW performance, 960 1215 MHz, 50 V, single side, 128 µs pulse width, 10% duty cycle
 - Output power at P_{3dB} = 1400 W
 - Efficiency = 68%
 - Gain = 17 dB
- Pb-free and RoHS compliant





GTVA101K42EV Package H-36275-4

Target RF Characteristics

Pulsed CW Specifications (tested in Wolfspeed test fixture) V_{DD} = 50 V, I_{DQ} = 200 mA, P_{OUT (P3dB)} = 1400 W peak, f = 960 to 1215 MHz, pulse width = 128 µs, 10% duty cycle

Characteristic	Symbol	Min	Тур	Max	Unit
Linear Gain	G _{ps}	_	17	_	dB
Drain Efficiency	η_D	_	68	_	%

All published data at $T_{CASE} = 25^{\circ}C$ unless otherwise indicated

ESD: Electrostatic discharge sensitive device—observe handling precautions!

DDC Characteristics

Characteristic Conditions		Symbol	Min	Тур	Max	Unit
Drain-source Breakdown Voltage	V_{GS} = -8 V, I _D = 100 mA	V _{(BR)DSS}	150	—	—	V
Drain-source Leakage Current	$V_{GS} = -8$ V, $V_{DS} = 10$ V	I _{DSS}	_	_	5	mA
Gate Threshold Voltage	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 200 \text{ mA}$	V _{GS(th)}	-3.8	-3.0	-2.7	V

Recommended Operating Conditions

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Drain Operating Voltage		V _{DD}	0	—	55	V
Gate Quiescent Voltage	$V_{DS} = 50 \text{ V}, \text{ I}_{D} = 200 \text{ mA}$	V _{GS(Q)}	_	-3.1	_	V

Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Drain-source Voltage	V _{DSS}	125	V
Gate-source Voltage	V _{GS}	-10 to +2	V
Gate Current	I _G	TBD	mA
Drain Current	۱ _D	TBD	А
Junction Temperature	TJ	225	°C
Storage Temperature Range	T _{STG}	-65 to +150	°C

Operation above the maximum values listed here may cause permanent damage. Maximum ratings are absolute ratings; exceeding only one of these values may cause irreversible damage to the component. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. For reliable continuous operation, the device should be operated within the operating voltage range (V_{DD}) specified above.

Thermal Chracteristics

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction to Case	$R_{ ext{ heta}JC}$	TBD	°C/W

Ordering Information

Type and Version	Order Code	Package Description	Shipping
GTVA101K42EV V1 R0	TBD	H-36275-4, bolt-down	Tape & Reel, 50 pcs
GTVA101K42EV V1 R2	TBD	H-36275-4, bolt-down	Tape & Reel, 250 pcs

Evaluation Boards

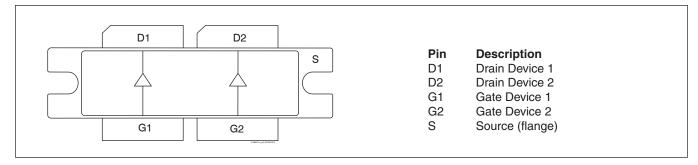
Order Code Frequency		Description		
LTN/GTVA101K42EV E1	960 – 1215 MHz	Class AB, combined outputs, RO4350B, 0.508mm thick		
LTN/GTVA101K42EV E2	1030 MHz	Class AB, combined outputs, RO4350B, 0.508mm thick		

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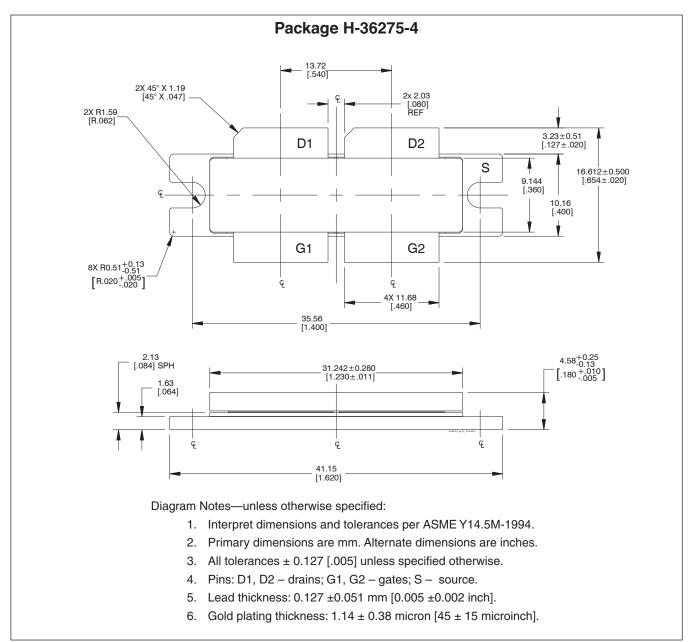


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Pinout Diagram (top view)



Package Outline Specifications



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Revision History

Revision	Date	Data Sheet Type	Page	Subjects (major changes since last revision)
01	2016-10-13	Advance	All	Data Sheet reflects advance specification for product development
01.1	2017-07-31	Advance	2	Added evaluation boards information
02	2018-05-01	Advance	All, 2, 3	Converted to Wolfspeed Data Sheet, updated DC characteristics and max ratings table format, added pinout diagram

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Notes

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